

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Stephen W. Bedell, et al.

Examiner: Unassigned

Serial No: To be assigned

Art Unit: Unassigned

Filed: Herewith

Docket: YOR920030102US2 (16476Z)

For: FORMATION OF SILICON-GERMANIUM-
ON-INSULATOR (SGOI) BY AN INTEGRAL
HIGH TEMPERATURE SIMOX-Ge INTERDIFFUSION
ANNEAL

Dated: October 29, 2003

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Sir:

In connection with filing the above-identified application under 37 C.F.R.
§1.53(b), applicants submit the following amendments and remarks for consideration by
the Examiner and entry of record in the above-identified patent application.

CERTIFICATE OF MAILING BY "EXPRESS MAIL"

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Dated: October 29, 2003


Steven Fischman